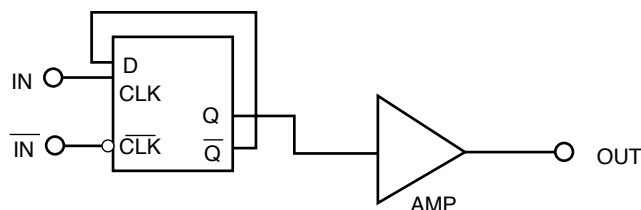


3.0 GHz DIVIDE BY 2 PRESCALER

FEATURES

- **HIGH FREQUENCY OPERATION TO 3 GHz**
- **FIXED DIVIDE RATIO: $\div 2$**
- **LOW CURRENT CONSUMPTION: 12 mA at 5 V**
- **SMALL PACKAGE: 8 pin SSOP**
- **AVAILABLE IN TAPE AND REEL**

INTERNAL BLOCK DIAGRAM



DESCRIPTION

The UPB1508GV is a Silicon RFIC digital prescaler manufactured with the NESAT™ IV silicon bipolar process. It features frequency response to 3 GHz, a divide-by-two ratio, and operates on a 5 volt supply while drawing only 12 mA. The device is housed in a small 8 pin SSOP package that contributes to system miniaturization. The low power consumption and wide frequency operation makes the device well suited for use in a PLL synthesizer for UHF/VHF TV and DBS tuner applications.

ELECTRICAL CHARACTERISTICS ($T_A = -40$ to $+85^\circ\text{C}$, $V_{CC} = 4.5$ to 5.5 V, $Z_s = Z_L = 50 \Omega$)

| PART NUMBER PACKAGE OUTLINE | | | UPB1508GV S08 | | |
|--------------------------------|---|------------|------------------|-----|----------|
| SYMBOLS | PARAMETERS AND CONDITIONS | UNITS | MIN | TYP | MAX |
| I_{CC} | Supply Current | mA | 7.6 | 12 | 14.5 |
| $f_{IN (U)}$ | Upper Limit Operating Frequency, $P_{IN} = -10$ to $+6$ dBm $P_{IN} = -15$ to $+6$ dBm | GHz GHz | 3.0 2.7 | | |
| $f_{IN (L)}$ | Lower Limit Operating Frequency, $P_{IN} = -15$ to $+6$ dBm | GHz | | | 0.5 |
| P_{IN} | Input Power, $f_{IN} = 2.7$ to 3.0 GHz $f_{IN} = 0.5$ to 2.7 GHz | dBm dBm | -10 -15 | | +6 +6 |
| P_{OUT} | Output Power, $P_{IN} = 0$ dBm, $f_{IN} = 2$ GHz | dBm | -12 | -7 | |

ABSOLUTE MAXIMUM RATINGS¹ (T_A = 25°C)

| SYMBOLS | PARAMETERS | UNITS | RATINGS |
|------------------|--------------------------------------|-------|-------------|
| V _{CC} | Supply Voltage | V | 6.0 |
| V _{IN} | Input Voltage | V | 6.0 |
| P _T | Total Power Dissipation ² | mW | 250 |
| T _{OP} | Operating Temperature | °C | -40 to +85 |
| T _{STG} | Storage Temperature | °C | -55 to +150 |

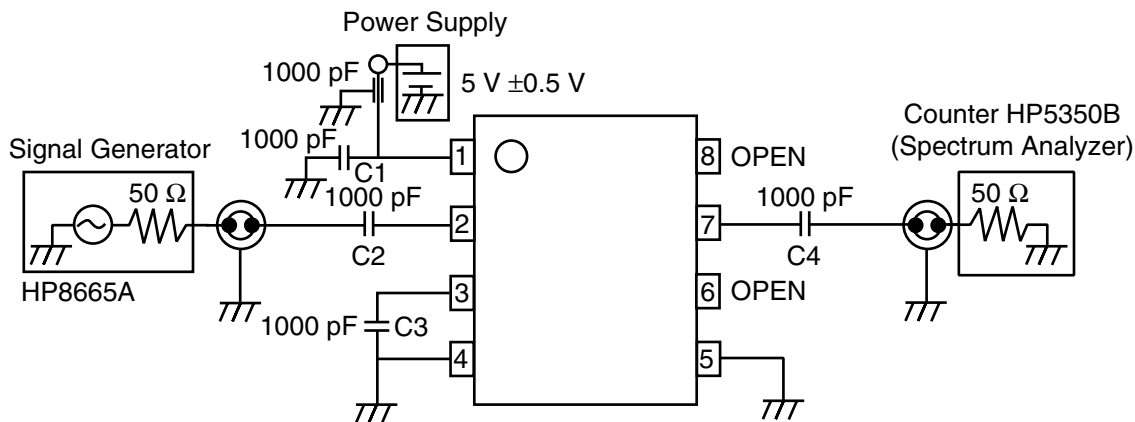
Notes:

1. Operation in excess of any one of these parameters may result in permanent damage.
2. Mounted on a double-sided copper clad 50x50x1.6 mm epoxy glass PWB (T_A = +85°C).

RECOMMENDED OPERATING CONDITIONS

| SYMBOL | PARAMETER | UNITS | MIN | TYP | MAX |
|-----------------|-----------------------|-------|-----|-----|-----|
| V _{CC} | Supply Voltage | V | 4.5 | 5.0 | 5.5 |
| T _{OP} | Operating Temperature | °C | -40 | +25 | +85 |

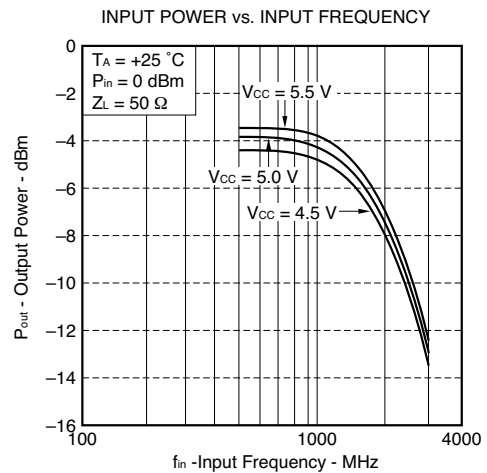
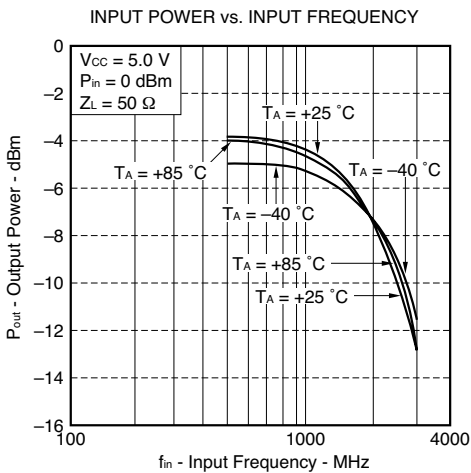
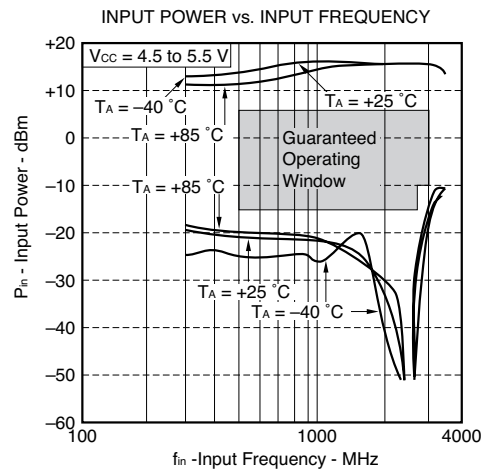
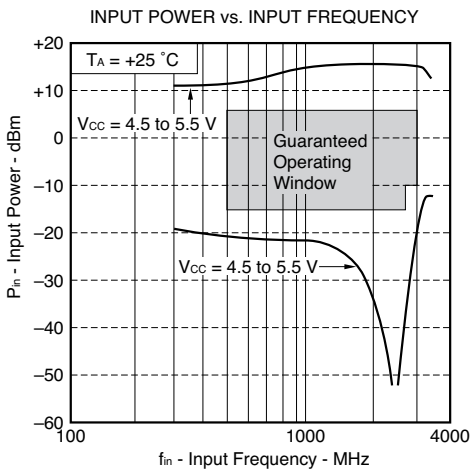
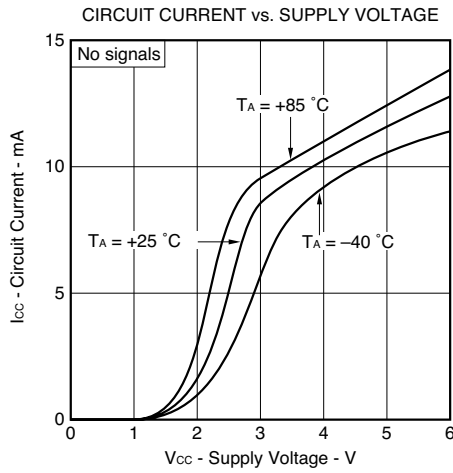
TEST CIRCUIT



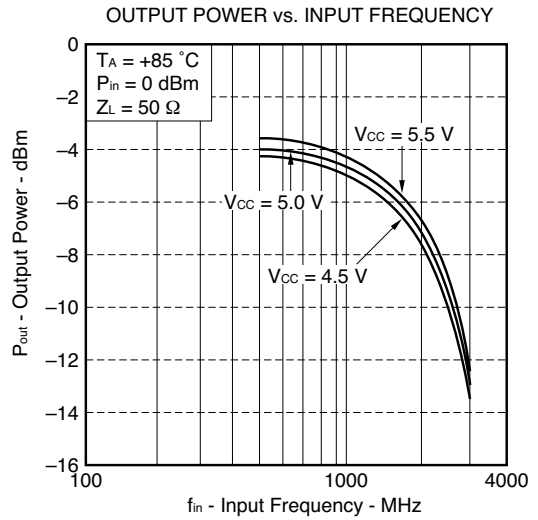
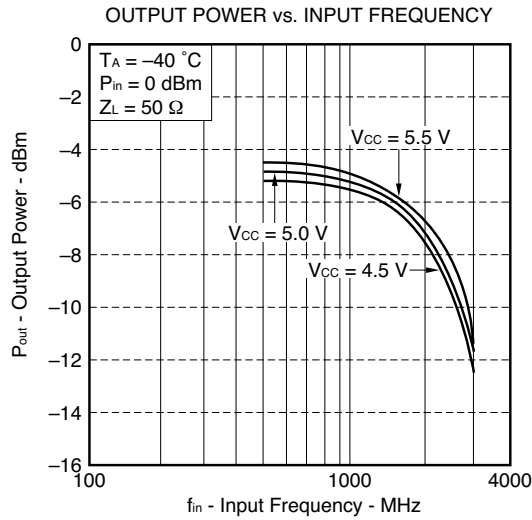
PIN DESCRIPTIONS

| Pin no. | Symbol | Applied Voltage | Pin Voltage | Description |
|---------|------------------------|-----------------|-------------|--|
| 1 | V _{CC} | 4.5 to 5.5 | | Power supply pin. This pin must be equipped with bypass capacitor (eg 1000 pF) to ground. |
| 2 | IN | | 1.7 to 4.95 | Signal input pin. This pin should be coupled with a capacitor (eg 1000 pF). |
| 3 | $\overline{\text{IN}}$ | | 1.7 to 4.95 | Signal input bypass pin. This pin must be equipped with a bypass capacitor (eg 1000 pF) to ground. |
| 4, 5 | GND | 0 | | Ground pin. Ground pattern on the board should be formed as wide as possible to minimize ground impedance. |
| 6 | NC | | | No connection. This pin should be left open. |
| 7 | OUT | | 1.0 to 4.7 | Divided frequency output pin. This pin should be coupled to load device with a capacitor (eg 1000 pF). |
| 8 | NC | | | No connection. This pin should be left open. |

TYPICAL PERFORMANCE CURVES (Unless otherwise specified, $T_A = 25^\circ\text{C}$)



TYPICAL PERFORMANCE CURVES (Unless otherwise specified, $T_A = 25\text{ }^\circ\text{C}$)



TYPICAL SCATTERING PARAMETERS ($T_A = 25\text{ }^\circ\text{C}$)

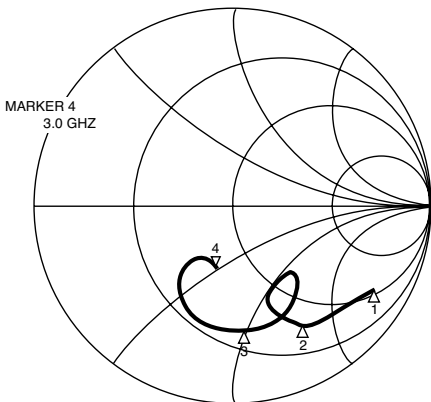
S11 vs. INPUT FREQUENCY
 $V_{CC} = 5.0\text{ V}$

S11 Z
 REF 1.0 Units
 2 200.0 mUnits/
 ▾ 34.604 Ω -26.496 Ω

hp

C

D



△₁ : 0.5 GHz
 △₂ : 1.0 GHz
 △₃ : 2.0 GHz
 △₄ : 3.0 GHz

START 0.500000000 GHz
 STOP 3.000000000 GHz

| FREQUENCY | | S11 | |
|-----------|-----|-------|--------|
| GHz | ANG | MAG | |
| 0.5 | | 0.850 | -30.2 |
| 0.6 | | 0.796 | -37.8 |
| 0.7 | | 0.790 | -39.2 |
| 0.8 | | 0.754 | -45.2 |
| 0.9 | | 0.766 | -53.7 |
| 1.0 | | 0.701 | -57.6 |
| 1.1 | | 0.660 | -62.3 |
| 1.2 | | 0.606 | -67.2 |
| 1.3 | | 0.571 | -70.3 |
| 1.4 | | 0.521 | -70.6 |
| 1.5 | | 0.495 | -68.3 |
| 1.6 | | 0.441 | -60.6 |
| 1.7 | | 0.479 | -45.1 |
| 1.8 | | 0.602 | -62.3 |
| 1.9 | | 0.595 | -74.2 |
| 2.0 | | 0.608 | -82.9 |
| 2.1 | | 0.603 | -89.8 |
| 2.2 | | 0.599 | -97.3 |
| 2.3 | | 0.588 | -107.7 |
| 2.4 | | 0.532 | -122.0 |
| 2.5 | | 0.396 | -132.0 |
| 2.6 | | 0.325 | -127.1 |
| 2.7 | | 0.270 | -123.6 |
| 2.8 | | 0.232 | -122.7 |
| 2.9 | | 0.258 | -105.8 |
| 3.0 | | 0.351 | -103.7 |

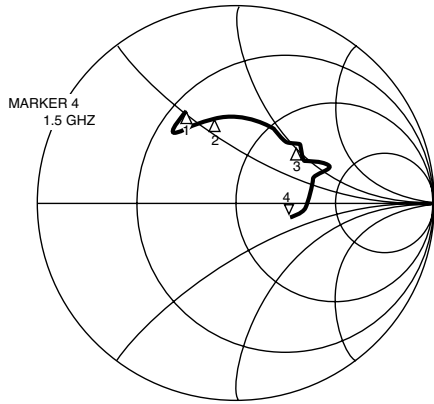
TYPICAL SCATTERING PARAMETERS (TA = 25 °C)

S22 vs. OUTPUT FREQUENCY

Vcc = 5.0 V, fin = 498 MHz

S22 Z
 REF 1.0 Units
 2 200.0 mUnits/
 ▽ 87.789 Ω -13.633 Ω
 hp

C
 D



START 0.250000000 GHz
 STOP 1.500000000 GHz

△₁ : 0.25 GHz
 △₂ : 0.50 GHz
 △₃ : 1.00 GHz
 △₄ : 1.50 GHz

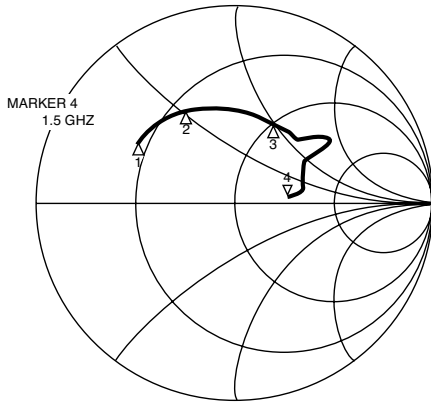
| FREQUENCY | | S22 | |
|-----------|-----|--------|-------|
| GHz | ANG | MAG | |
| 0.25 | | 0.526 | 118.9 |
| 0.30 | | 0.463 | 131.2 |
| 0.35 | | 0.466 | 124.7 |
| 0.40 | | 0.460 | 117.1 |
| 0.45 | | 0.441 | 110.2 |
| 0.50 | | 0.456 | 103.0 |
| 0.55 | | 0.353 | 94.8 |
| 0.60 | | 0.438 | 91.1 |
| 0.65 | | 0.444 | 83.9 |
| 0.70 | | 0.436 | 78.3 |
| 0.75 | | 0.435 | 71.8 |
| 0.80 | | 0.431 | 65.9 |
| 0.85 | | 0.431 | 60.3 |
| 0.90 | | 0.431 | 53.7 |
| 0.95 | | 0.408 | 49.2 |
| 1.00 | | 0.445 | 44.9 |
| 1.05 | | 0.428 | 41.0 |
| 1.10 | | 0.429 | 33.7 |
| 1.15 | | 0.355 | 42.7 |
| 1.20 | | 0.418 | 20.0 |
| 1.25 | | 0.403 | 17.1 |
| 1.30 | | 0.392 | 9.6 |
| 1.35 | | 0.368 | 3.3 |
| 1.40 | | 0.343 | -3.4 |
| 1.45 | | 0.319 | -9.2 |
| 1.50 | | 0.289- | 14.1 |

S22 vs. OUTPUT FREQUENCY

Vcc = 5.0 V, fin = 3002 MHz

S22 Z
 REF 1.0 Units
 2 200.0 mUnits/
 ▽ 91.109 Ω 2.6523 Ω
 hp

C
 D

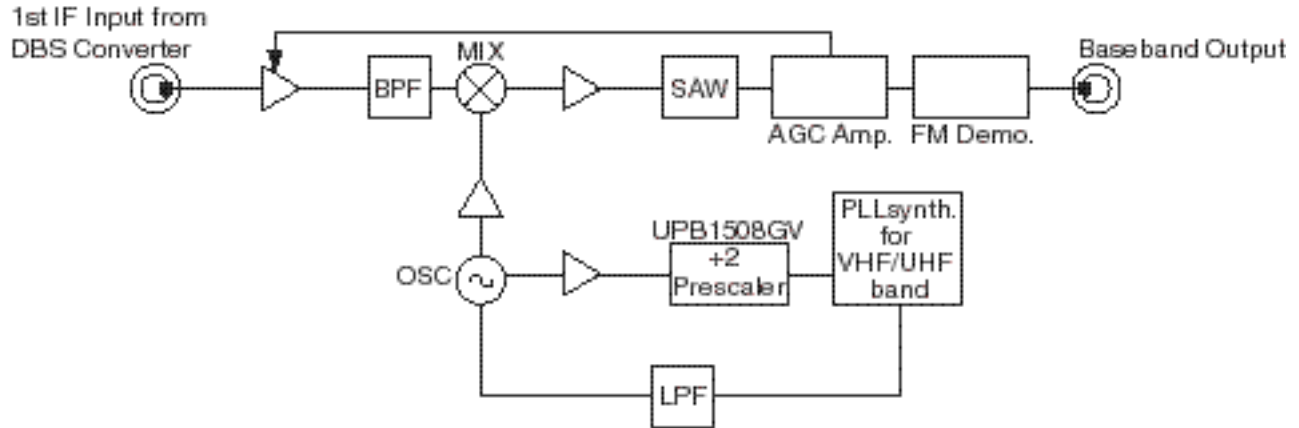


START 0.250000000 GHz
 STOP 1.500000000 GHz

△₁ : 0.25 GHz
 △₂ : 0.50 GHz
 △₃ : 1.00 GHz
 △₄ : 1.50 GHz

| FREQUENCY | | S22 | |
|-----------|-----|-------|-------|
| GHz | ANG | MAG | |
| 0.25 | | 0.555 | 146.6 |
| 0.30 | | 0.545 | 139.9 |
| 0.35 | | 0.571 | 136.1 |
| 0.40 | | 0.529 | 127.9 |
| 0.45 | | 0.521 | 122.4 |
| 0.50 | | 0.515 | 116.9 |
| 0.55 | | 0.510 | 104.5 |
| 0.60 | | 0.492 | 106.6 |
| 0.65 | | 0.487 | 100.9 |
| 0.70 | | 0.482 | 95.3 |
| 0.75 | | 0.473 | 89.9 |
| 0.80 | | 0.461 | 83.8 |
| 0.85 | | 0.454 | 78.4 |
| 0.90 | | 0.449 | 72.3 |
| 0.95 | | 0.430 | 69.6 |
| 1.00 | | 0.443 | 64.3 |
| 1.10 | | 0.440 | 52.3 |
| 1.15 | | 0.438 | 46.0 |
| 1.20 | | 0.501 | 37.5 |
| 1.25 | | 0.408 | 32.9 |
| 1.30 | | 0.388 | 25.1 |
| 1.35 | | 0.359 | 16.3 |
| 1.40 | | 0.335 | 9.7 |
| 1.45 | | 0.304 | 3.1 |
| 1.50 | | 0.285 | 4.6 |

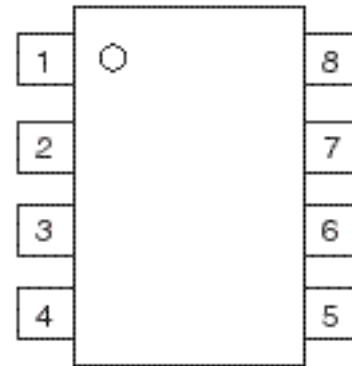
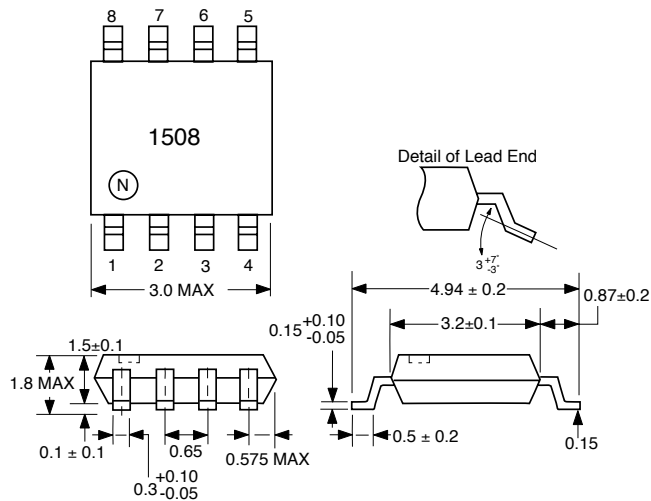
SYSTEM APPLICATION EXAMPLE



OUTLINE DIMENSIONS (Units in mm)

PIN CONNECTION

PACKAGE OUTLINE S08



PIN CONNECTIONS

- 1. Vcc
- 2. IN
- 3. $\bar{I}N$
- 4. GND
- 5. GND
- 6. NC
- 7. OUT
- 8. NC

ORDERING INFORMATION

| PART NUMBER | QUANTITY |
|----------------|-----------|
| UPB1508GV-E1-A | 1000/Reel |

Note:

- 1. Embossed tape 8 mm wide.
Pin 1 is in the tape pull-out direction.

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